

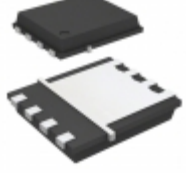
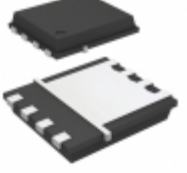
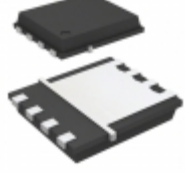
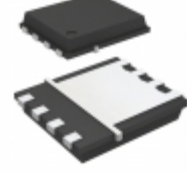
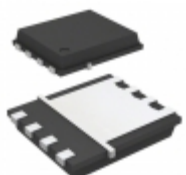
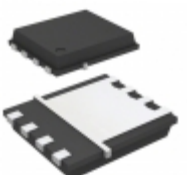
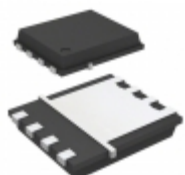
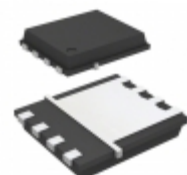
 	<h2 style="color: #E67E22;">FDMS86102LZ</h2> <p>Hersteller-Teilenummer: FDMS86102LZ</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 100V 7A 8-PQFN</p> <p>Datenblätter:  FDMS86102LZ.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 3063 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FDMS86102LZ
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 100V 7A 8-PQFN
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	3063 pcs Stock
Serie	PowerTrench®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-PowerTDFN
Supplier Device-Gehäuse	8-PQFN (5x6), Power56
Verlustleistung (max)	2.5W (Ta), 69W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	7A (Ta), 22A (Tc)
Rds On (Max) @ Id, Vgs	25 mOhm @ 7A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	22nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1305pF @ 50V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)





















FDMS86102LZ ist neu im Original, Suche FDMS86102LZ Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FDMS86102LZ Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FDMS86102LZ: Info@Y-IC.com

Sie können auch interessiert sein:

 FDMS86102LZ AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 7A 8-PQFN	 FDMS86101DC Fairchild/ON Semiconductor MOSFET N-CH 100V 14.5A 8-PQFN	 FDMS86103L AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 12A POWER56	 FDMS86105 Fairchild/ON Semiconductor MOSFET N-CH 100V POWER56
 FDMS86101DC AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 14.5A 8-PQFN	 FDMS86101A Fairchild/ON Semiconductor MOSFET N-CH 100V 13A POWER56	 FDMS86104 Fairchild/ON Semiconductor MOSFET N-CH 100V 7A POWER56	 FDMS86103L Fairchild/ON Semiconductor MOSFET N-CH 100V 12A POWER56

heiße Teile

Mehr

 FDMS8050	 FDMS8050ET30	 FDMS8050ET30	 FDMS8320L	 FDMS8320L
 FDMS8322	 FDMS8333L	 FDMS8333L	 FDMS8460	 FDMS8460
 FDMS8460S	 FDMS8558S	 FDMS8558S	 FDMS8558SDC	 FDMS8558SDC
 FDMS8560S	 FDMS8560S	 FDMS8570S	 FDMS8570S	 FDMS86101
 FDMS86101	 FDMS86101A	 FDMS86101A	 FDMS86101DC	 FDMS86101DC
 FDMS86102LZ	 FDMS86103L	 FDMS86103L	 FDMS86104	 FDMS86104
 FDMS86105	 FDMS86105	 FDMS86150	 FDMS86150	 FDMS86152
 FDMS86152	 FDMS86181	 FDMS86181	 FDMS86182	 FDMS86183
 FDMS86200	 FDMS86200	 FDMS86201	 FDMS86201	 FDMS86222
 FDMS8622	 FDMS86250	 FDMS86250	 FDMS86257	 FDMS86300

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